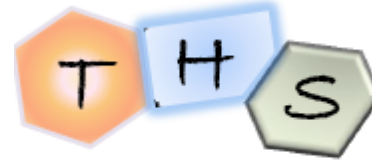




PHYSIKALISCHES INSTITUT  
DER UNIVERSITÄT WIEN



Tailored  
Hybrid  
Structures



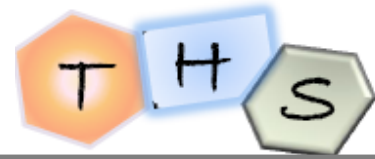
Paola Ayala

**C, B, N and P:**

***“Low Doping vs. Heteronanotubes”***

Workshop Carbon Nanotube Growth, Separation and Spectroscopy

*The University of Tokyo, 05.10.2012*



# OUTLINE

## State of the art

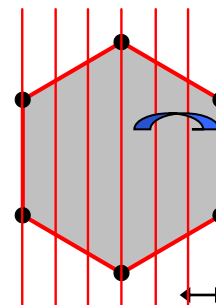
- Morphological characteristics
- Theoretical approaches
- Successful experimental attempts, Experimental data

## Our Samples: Experimental Evidence of SW doped CNTs

- Sample morphology: SWNT/MWNT
- Diameter/diameter distribution and defect concentration
- Heteroatom-content, doping environment

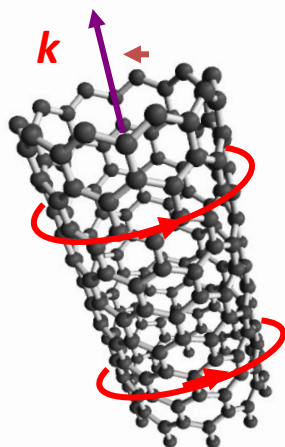
## Future Perspectives regarding doped CNTs

# Electronic Properties and Structure of SWNTs

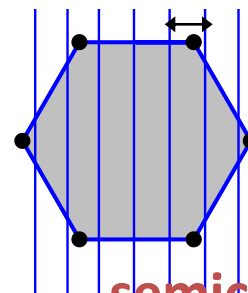
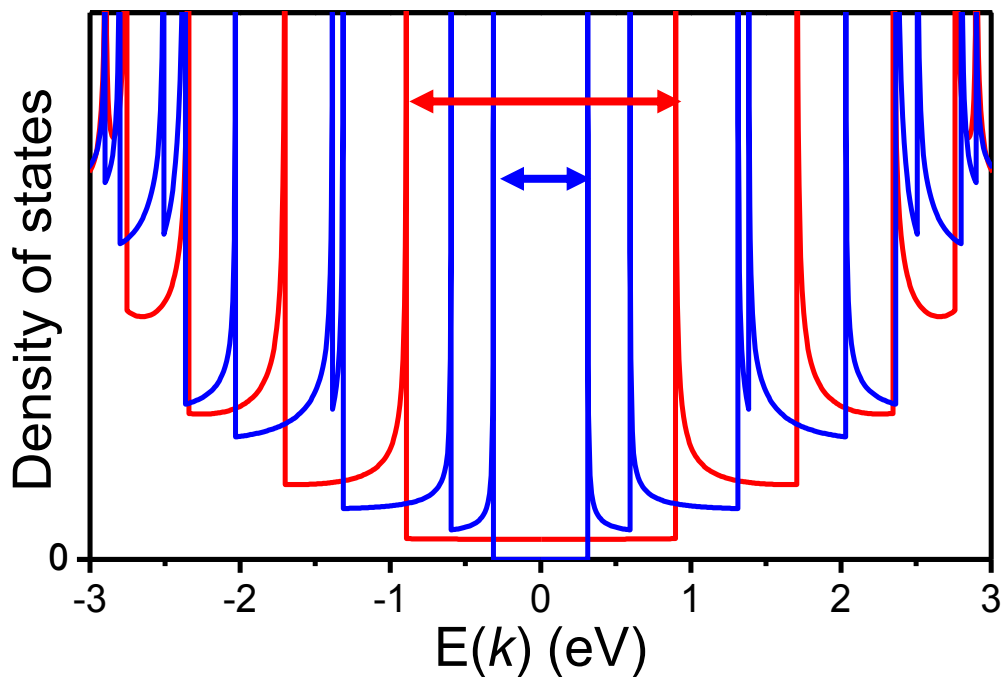


1/3

metal



$\sigma$ -bands:  $\sim 50$  eV  
 $\pi$ -bands:  $\sim 20$  eV



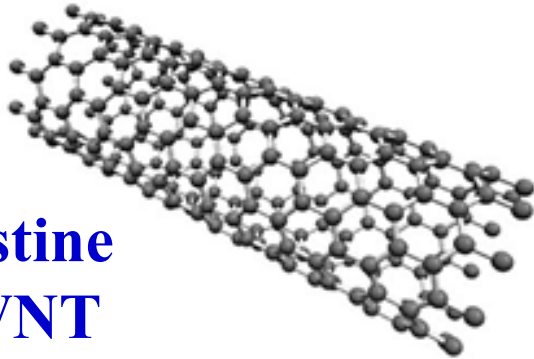
2/3

semiconductor

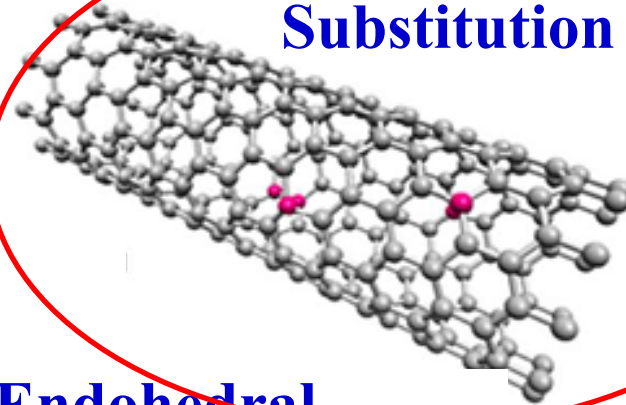
Electronic properties fully determined by geometry!!!

# Modifications to induce changes in the electronic structure...

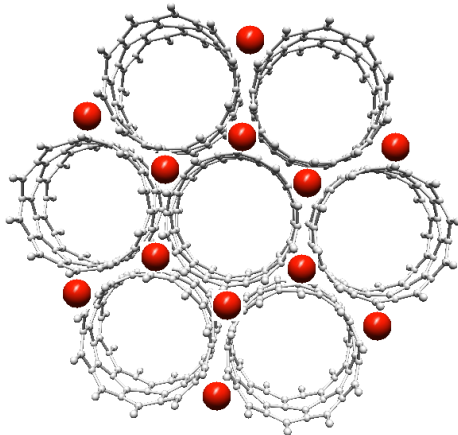
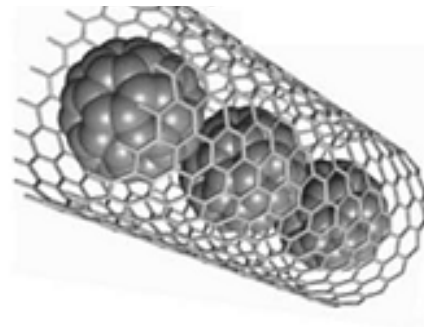
**Pristine  
SWNT**



**Substitution**



**Endohedral  
doping**



**Intercalation**

P.Ayala, et al., **Reviews of Modern Physics** 82(2010)1843-1885.  
P.Ayala, et al., **Carbon**, 41 (2010) 1853.

# Doping with N, B, P?

**Different features in MW and SW doped nanotubes.**

## •SWNTs

Sharp localized states above and below the Fermi level (n- or p-type doping), by substitution or removal of C atoms.

## •MWNTs

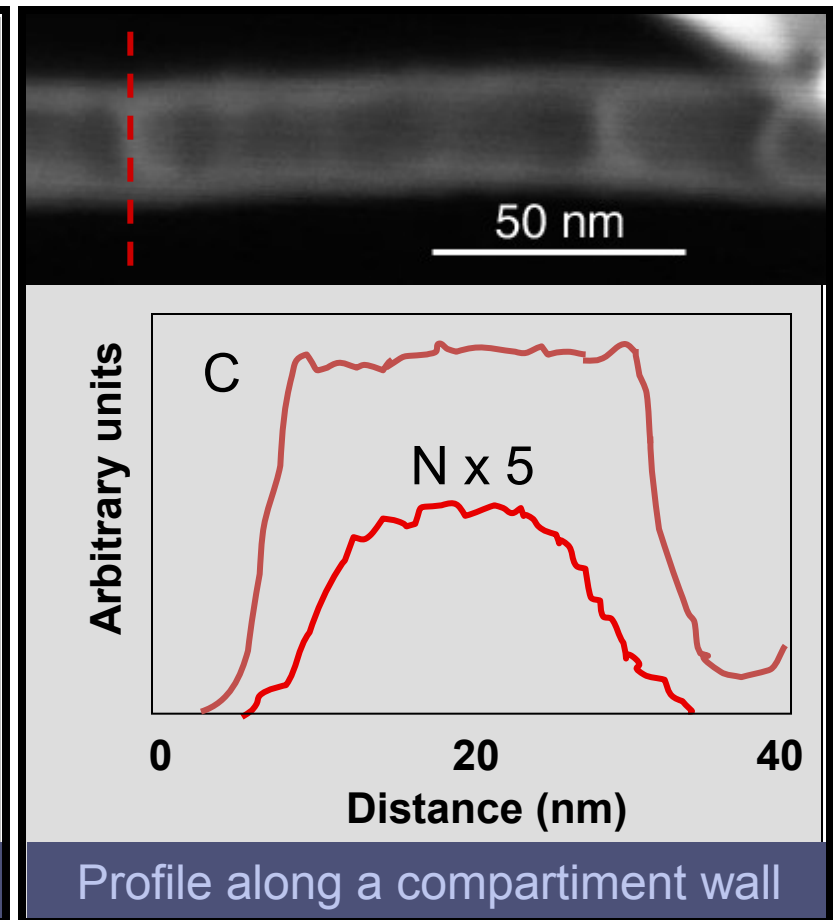
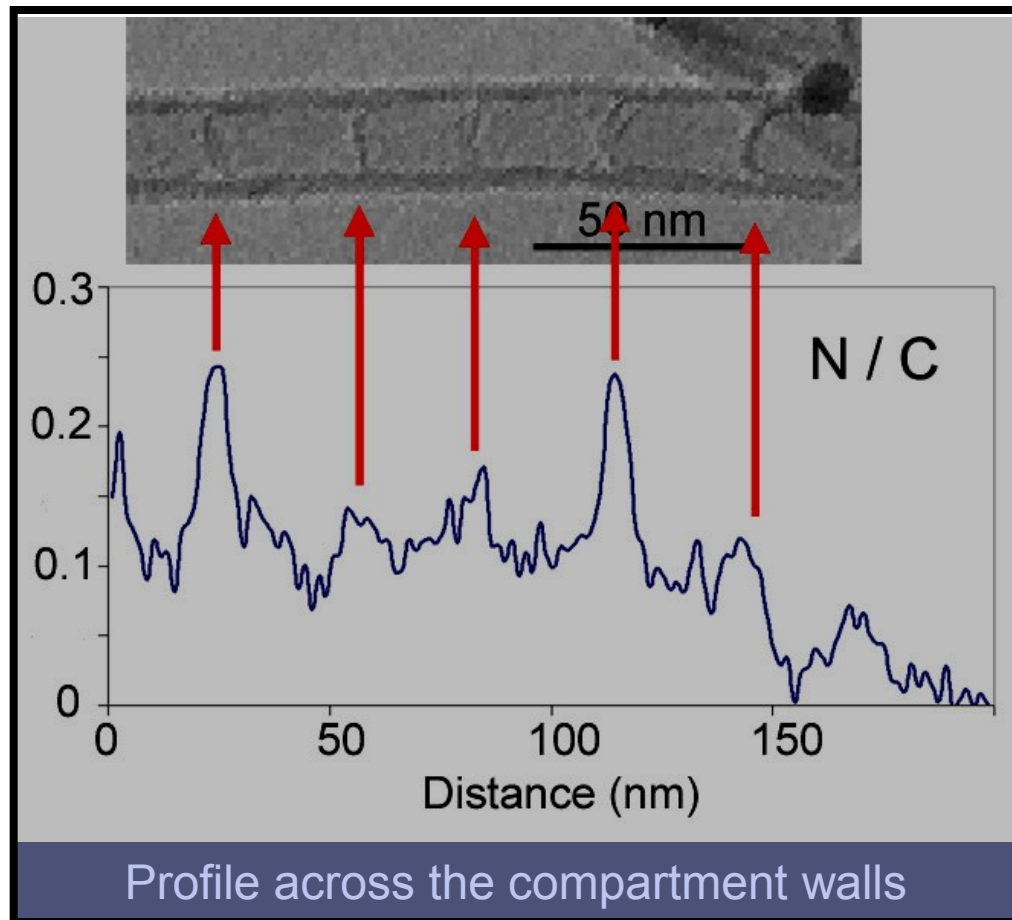
Gain of electrochemical reactivity,

Functionalization for further applications.

			8	9	10
			O	F	Ne
			16.00	19.00	20.18
13	14	15	16	17	18
Al	Si	P	S	Cl	Ar
26.98	28.09	30.97	32.07	35.45	39.95
31	32	33	34	35	36
Ga	Ge	As	Se	Br	Kr
69.72	72.61	74.92	78.96	79.90	83.80
49	50	51	52	53	54
In	Sn	Sb	Te	I	Xe
114.8	118.7	121.8	127.6	126.9	131.3
81	82	83	84	85	86
Tl	Pb	Bi	Po	At	Rn
204.4	207.2	209.0	209.0	210.0	222.0
113	114	115	116	117	118
Uut	Uuq	Uup	Uuh	Uus	Uuo
	289		289		293

5 B 10.81	6 C 12.01	7 N 14.01
P		

# How much N can we incorporate **Substitutionally**?



## Observations for MW-CN<sub>x</sub>-CNTs

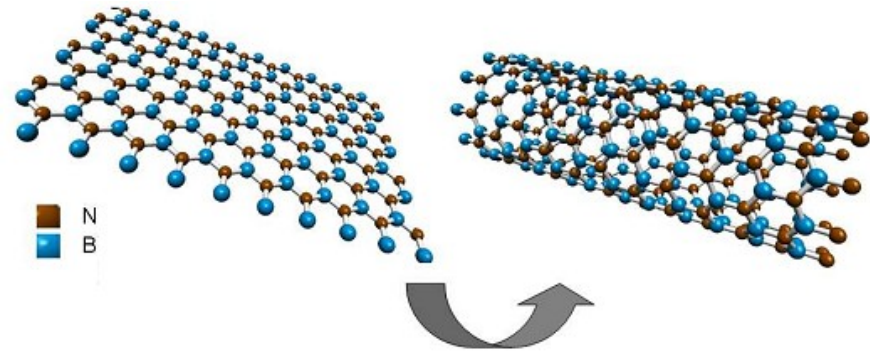
- N is dominantly localized in the compartments
- Doping can reach 25 %

*Courtesy: Prof. Christian Colliex.  
(LPS-Orsay)- CIASEM 2005.  
Havana*

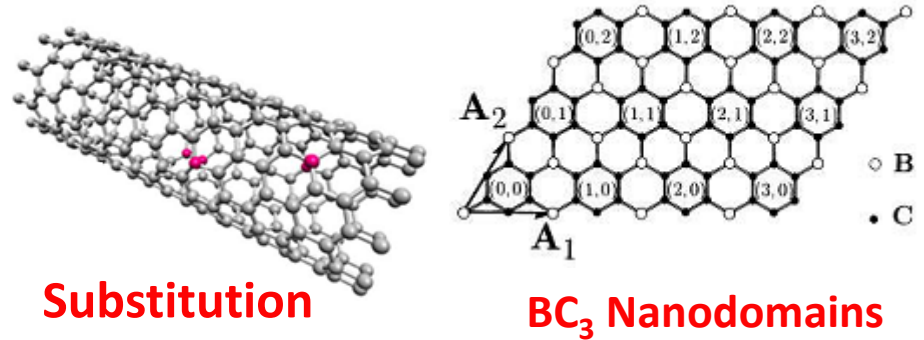


We are dealing here with graphitelike planar structures that resemble the geometry of a honeycomb.

## BN-Nanotubes



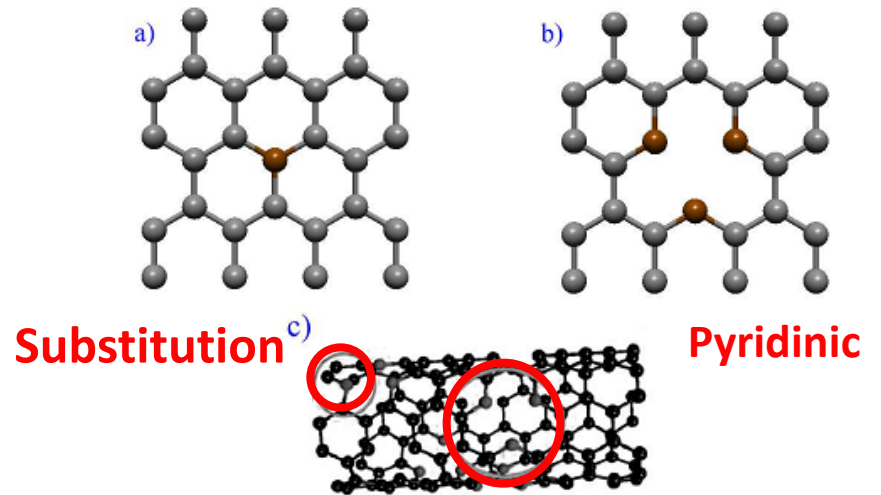
## Boron Doping



Substitution

BC<sub>3</sub> Nanodomains

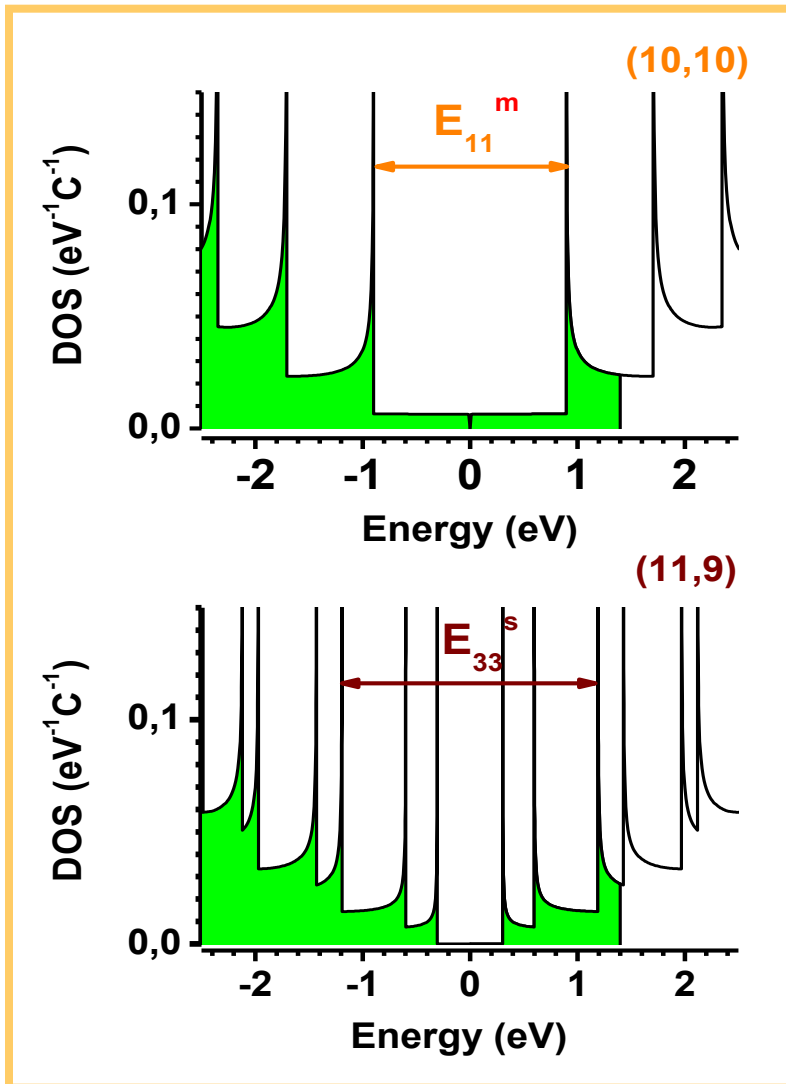
## Nitrogen Doping



Substitution<sup>c)</sup>

Pyridinic

## Changing Electronic Properties by **substitutional** doping

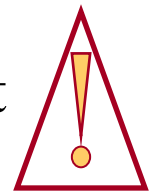


### Low doping levels

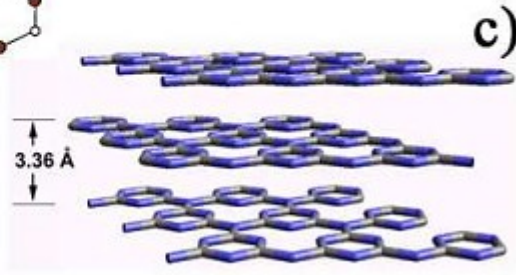
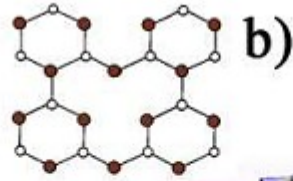
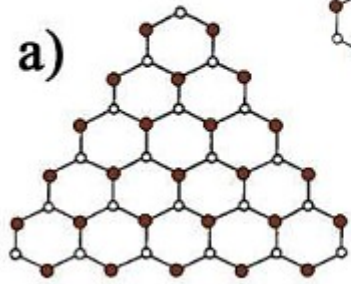
- Semiconductor Industry
- Rigid band model

### High doping levels

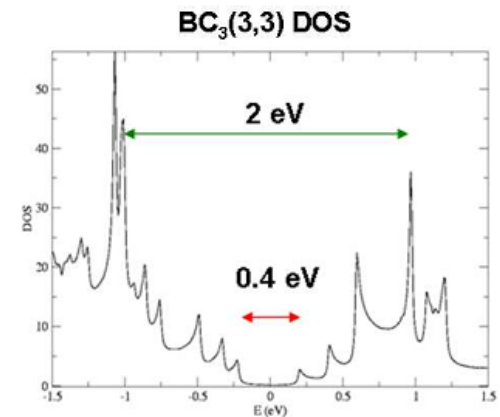
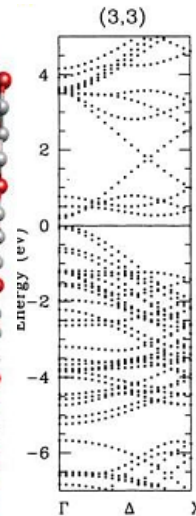
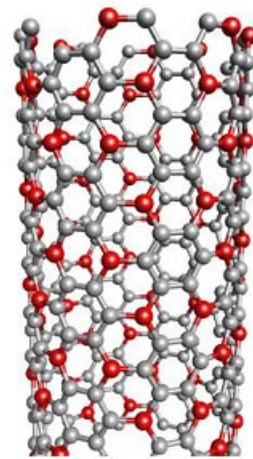
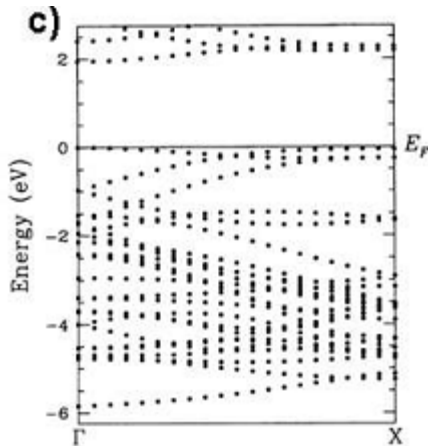
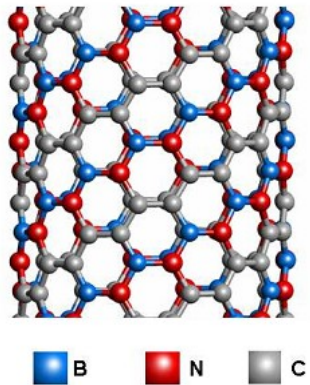
- Chemistry: New stable structures
- Rigid band model not applicable !!!







Hexagonal graphitic-like planar structures should be able to generate nanotubules with different stoichiometries based on B, C and N

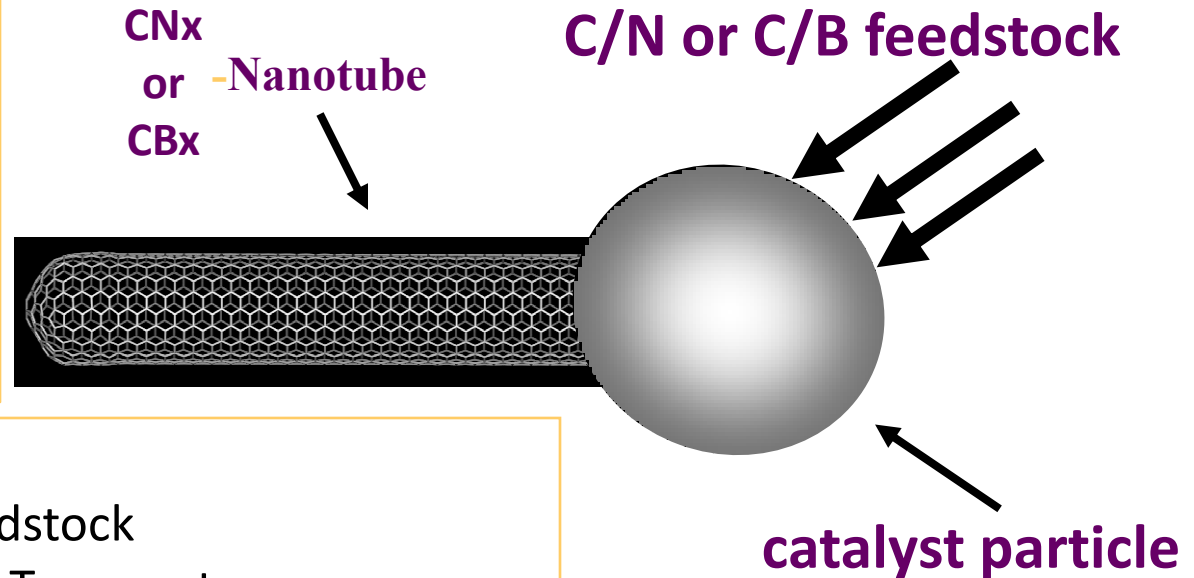


The incorporation of foreign atoms such as B and N can break the stability of a planar structures depending on the site they enter.

# CNx and CBx Nanotubes Synthesis

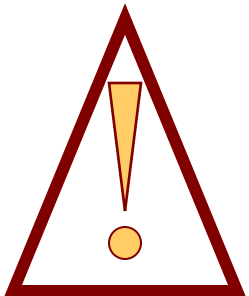
## Successful Attempts

- Laser Ablation
- Arc Discharge
- CVD / AA-CVD
- Spray Pyrolysis
- Ball Milling (CBx)
- Substitution Reactions ( $BC_3$ )



## Parameters to control:

- Vapor pressure C/N Feedstock
- Feedstock Self-Pyrolysis Temperature
- Catalyst Composition and Activity
- Catalyst pre-treatment



A pure C/N feedstock is needed to determine the N incorporation profile within the tubes.

**Benzylamine (2%at.)**

**Acetonitrile (6%at.)**

**Triisopropyl Borate (4% at.)**

# Substitutionally doped SWNTs: Challenges

**Is it possible  
to have  
substitutional  
doping?**

**What is  
the best  
synthesis  
method?**

**Low  
substitutional  
doping**

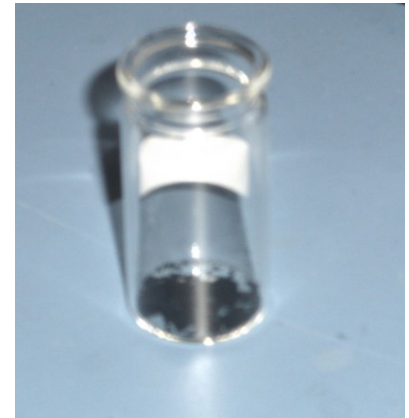
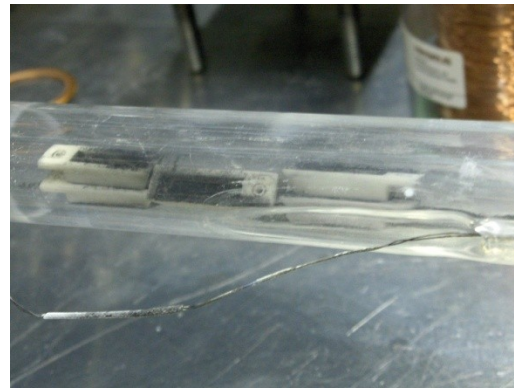


**What kind  
of  
precursor  
is ideal?**

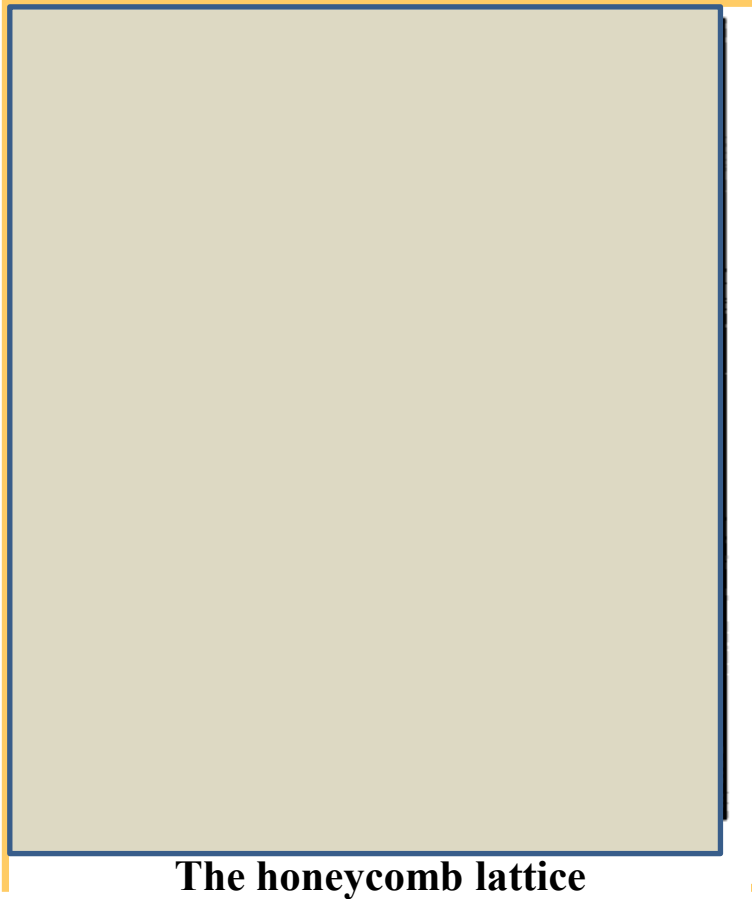
**Characterize  
efficiently  
low doping  
levels**

# Sample Characterization

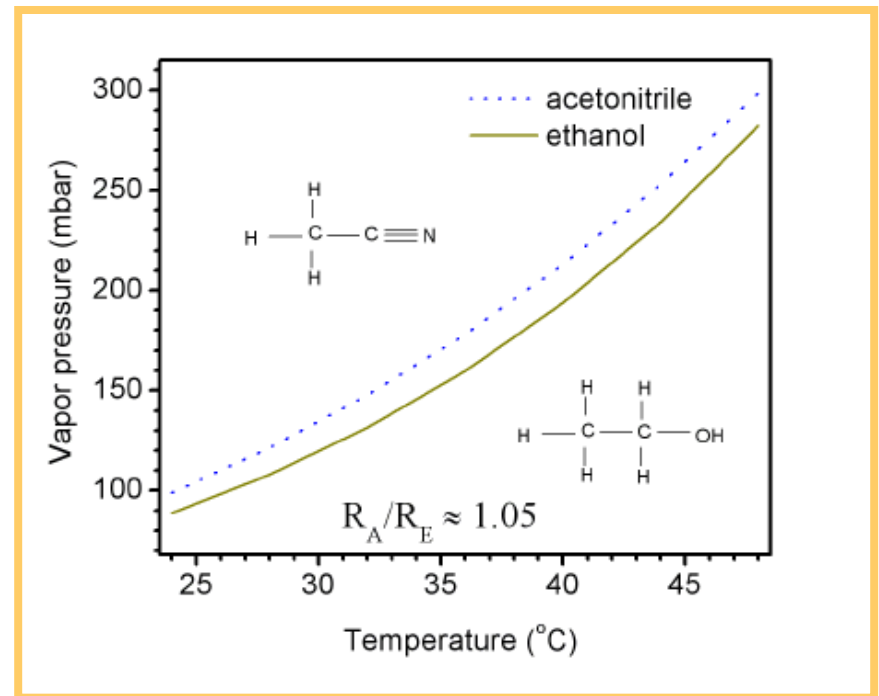
- **Morphology:**  
SEM(Bulk)/TEM (Local)
- **Diameter and defect concentration:**  
Raman Spectroscopy  
(Bulk sensitive)
- **Doping level**  
TEM-EELS (?)  
XPS



# The Reaction Atmosphere



- Is N incorporation really energetically disfavored?
- Is it possible to synthesize N and B-doped SWNTs?



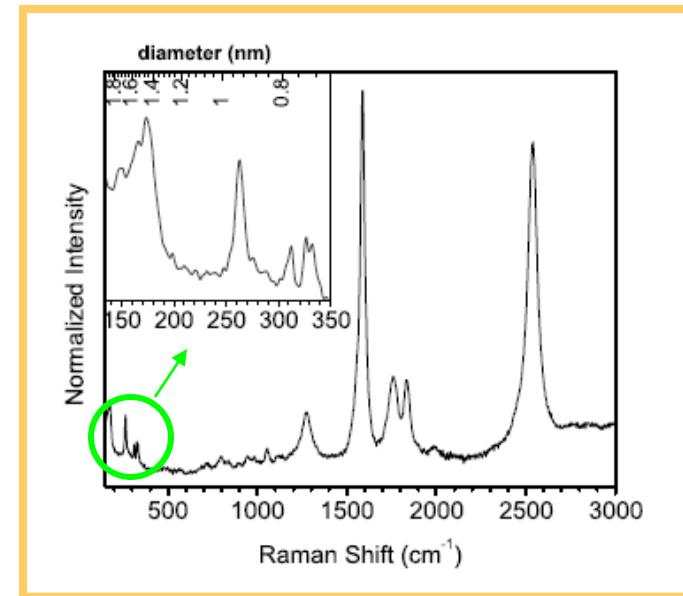
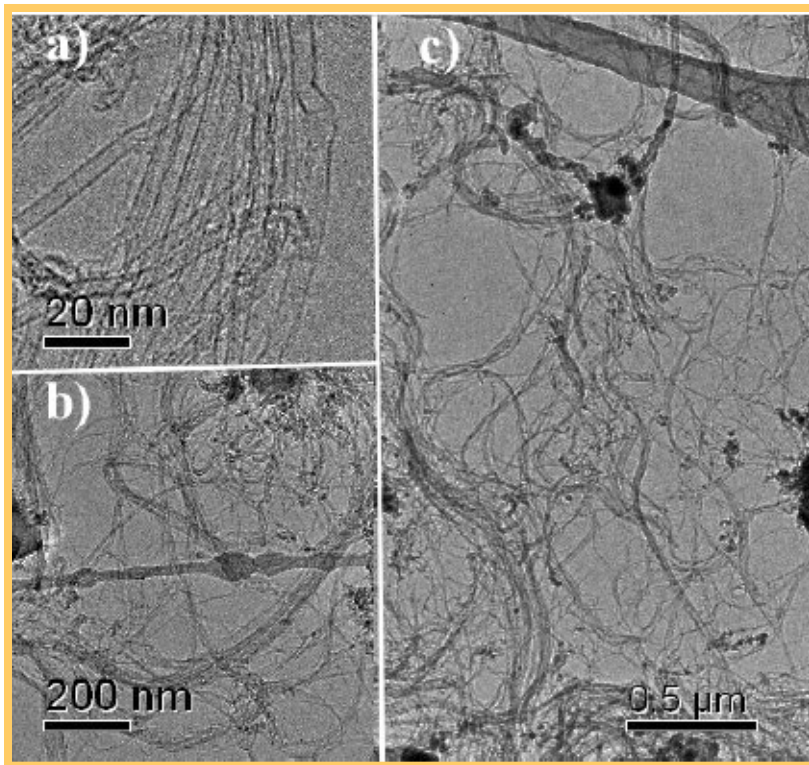
P. Ayala, et al. J. Chem Physics 127 (2007) 184709

P. Ayala, et al.. Chem Mater 19(2007) 6131

P. Ayala, et al. J. Phys Chem C 101(2007)2879

# Effects of the Reaction Atmosphere Composition

## Pure Ethanol Nanotubes...



- Growth: Between 800 and 1050°C
- High yield of SWNTs

Raman: 0.8 to 2nm

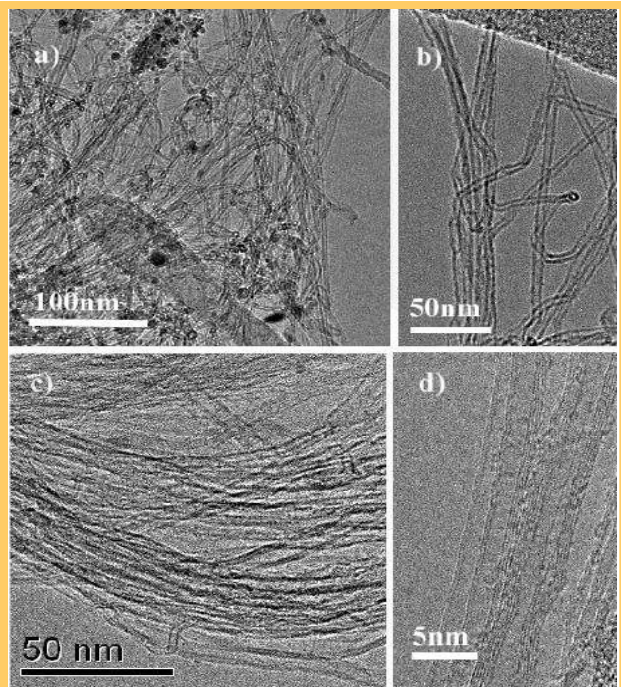
TEM: Bundles



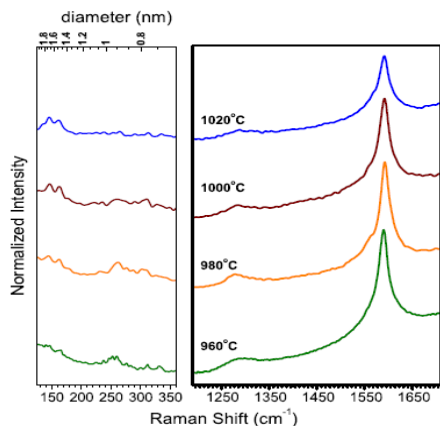
# Composed Feedstocks

1

Ethanol rich source  
(10%wt acetonitrile)



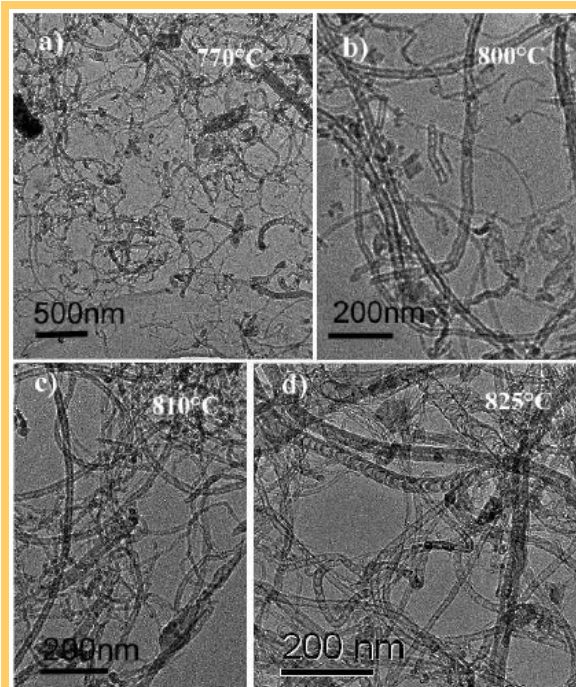
- Onset for NT growth: 880°C
- TEM: SWNTs and low amount of MWNTs



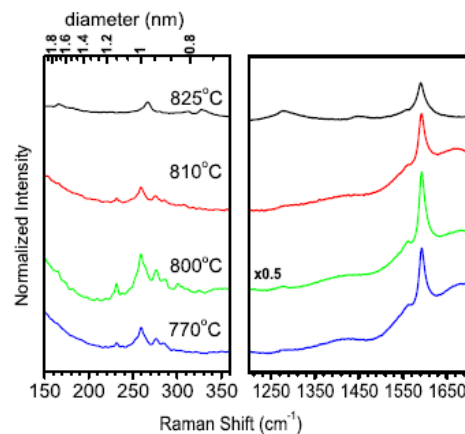
- Constant D/G with temperature
- Onset for MWNTs growth 1020°C

2

Equally contributing composition  
(1:1 acetonitrile vs ethanol)



- Multiple morphology product independent of synthesis T
- Lower T, ~5% of short (500nm) and thin nanotubes (~1-15nm)



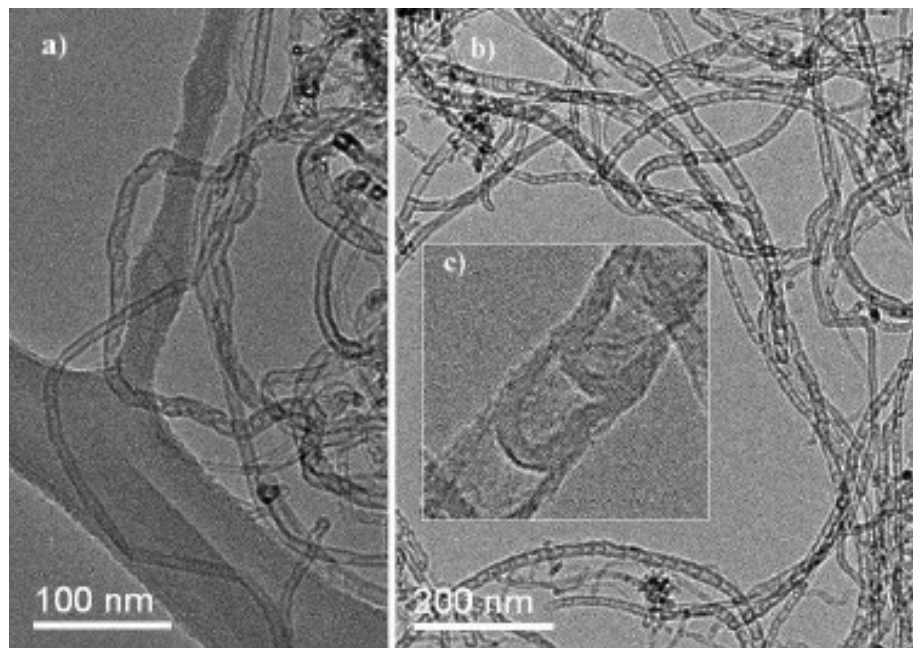
- Highest SWNTs Raman response at 800°C
- Low formation of SWNTs at higher temperatures
- SWNT grow T-window narrows down.



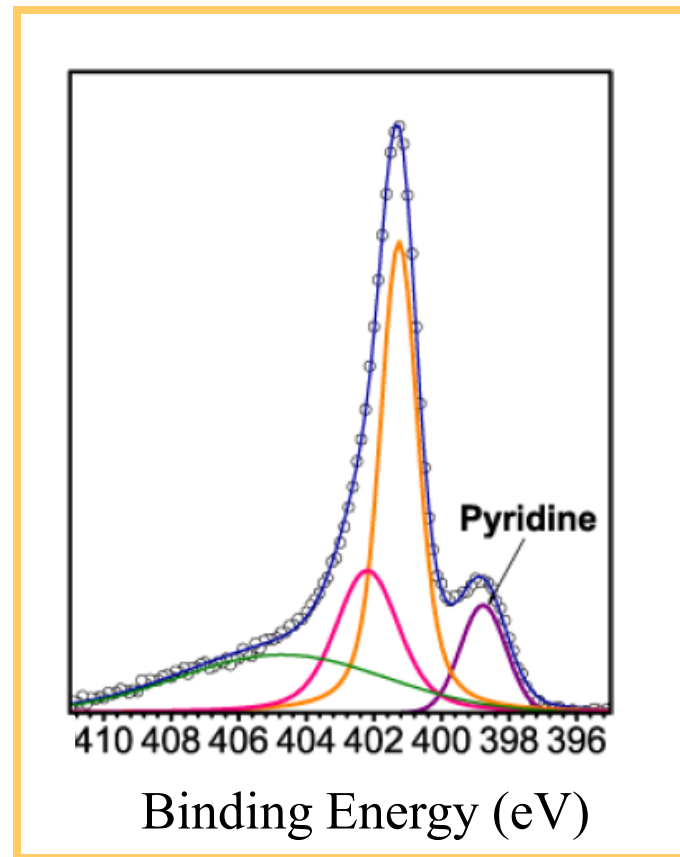
3

# Pure C/N feedstock

## Pure acetonitrile feedstock....



- Practically no evidence of SWNTs
- MWNTs grow between 750 and 900°C
- Morphology:  
Defective MWNTs and bamboo-like tubes with diameters between 15 to 20nm.

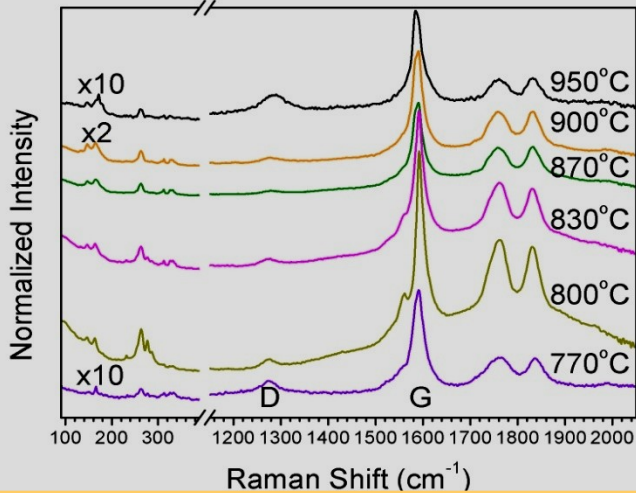


Max N content:

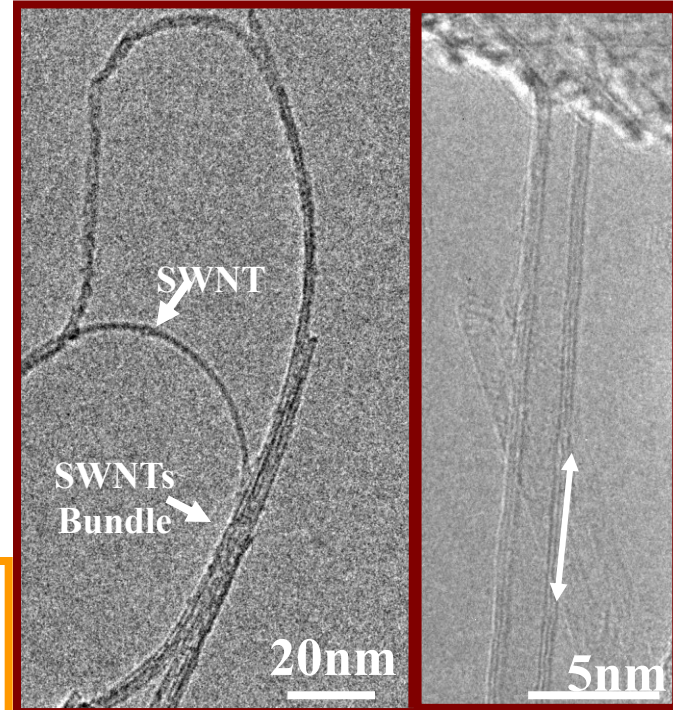
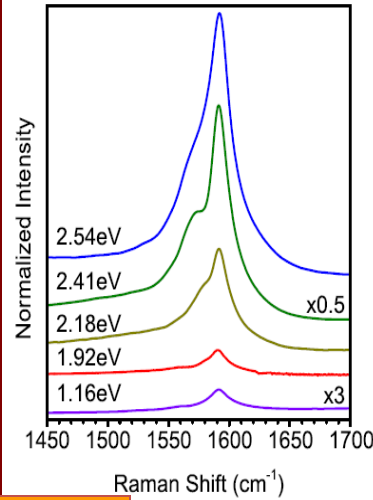
Composed Feedstocks ~1.5 0.2%at.  
Pure Acetonitrile Feedstock ~1.7%at  
C1s: 284.7eV at all T

# Benzylamine CNx-nanotubes

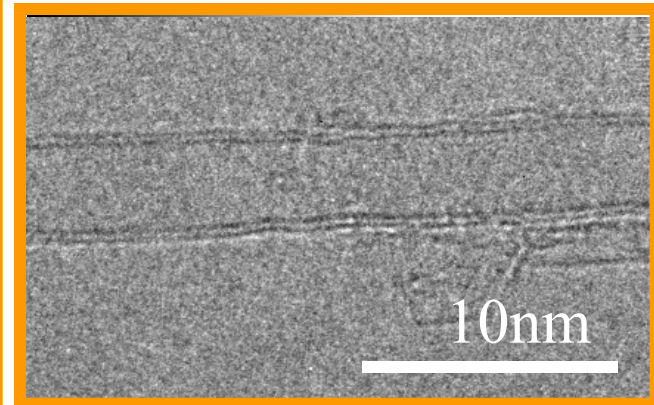
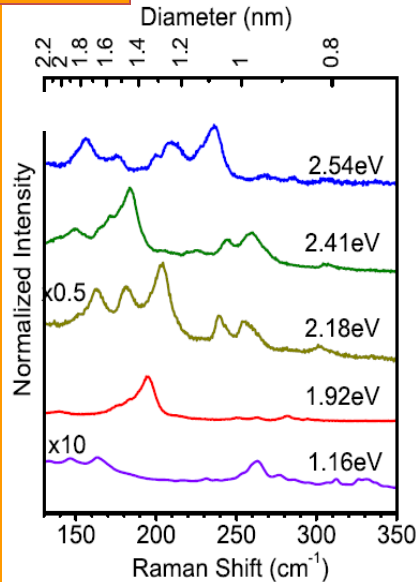
## FT-Raman Spectra



## Multifrequency Raman...An insight to diameter distribution



830°C



### •Radial Breathing Mode Response

DWNT /SWNT optimum growth:  
800°C to 900°C.

### •Highest yield

870°C of DWCNT ( $320\text{ cm}^{-1}$ )  
830°C of SWCNT ( $270\text{ cm}^{-1}$ )

### •Relative Nanotube Yield:

Maximum Raman response between  
800°C and 870°C

### •Relative defect concentration:

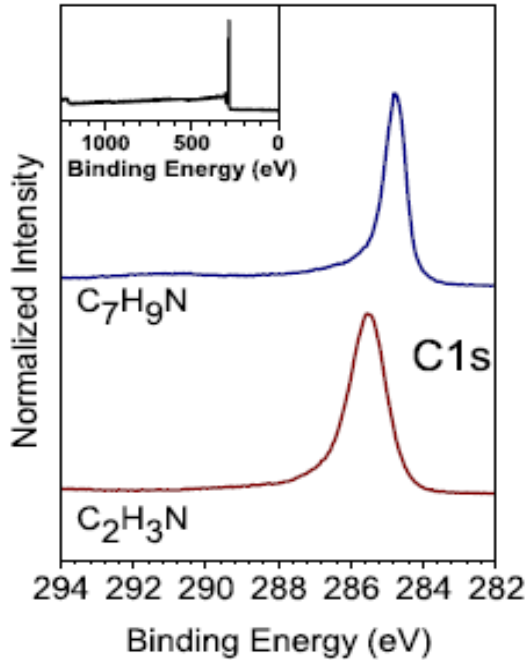
Low D/G ratio down to 1/20

# CNx NTs

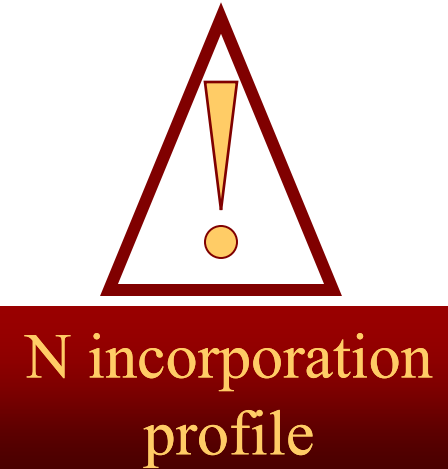
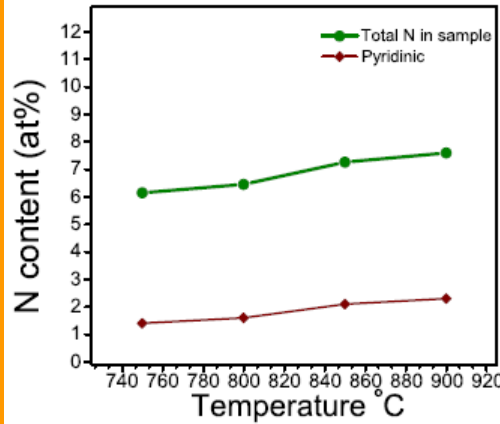
# Atomic composition: XPS

C

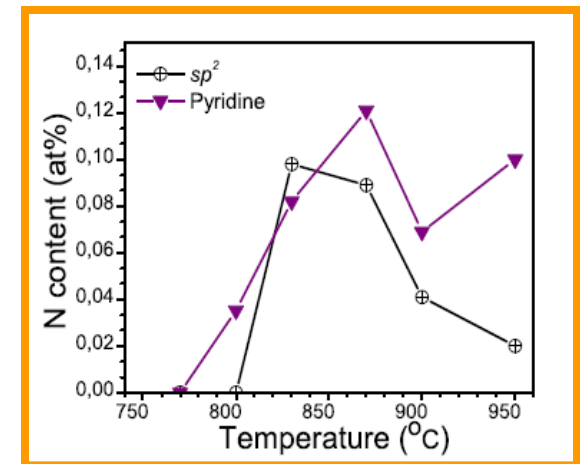
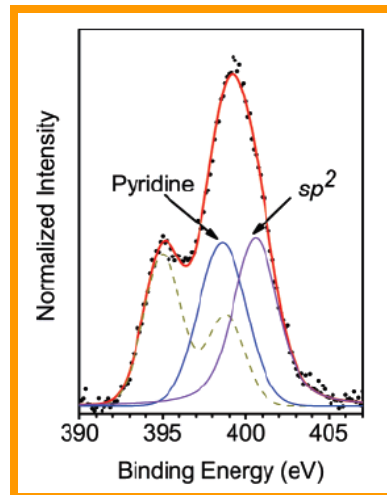
N



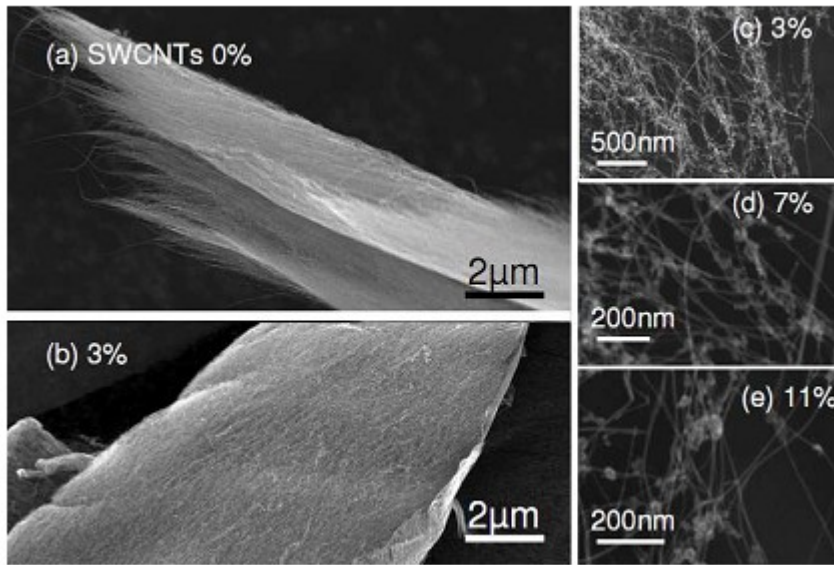
- Broadening of C1s peak at lower nanotube growth temperatures



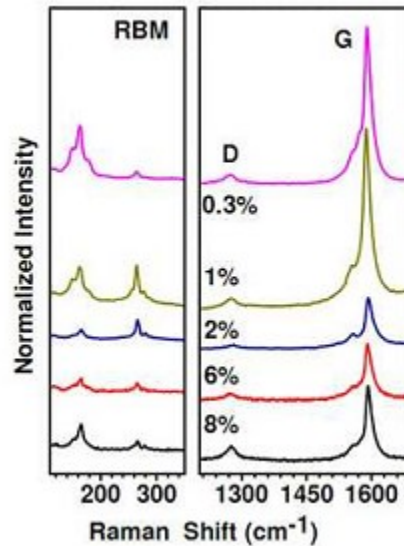
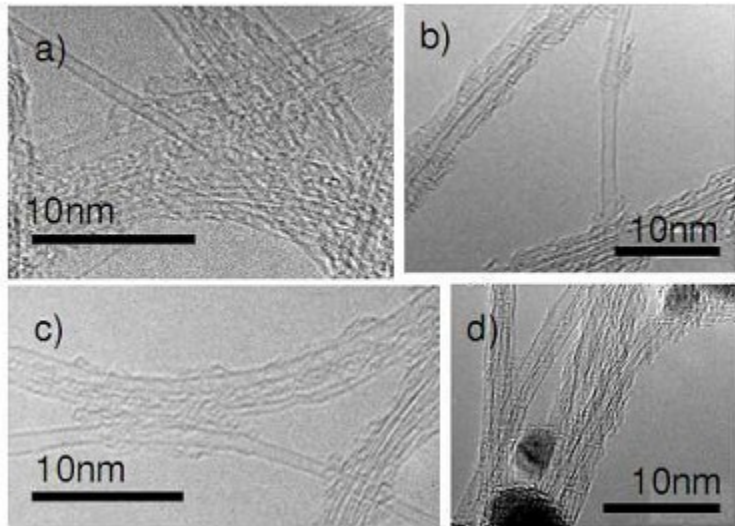
- *sp*<sup>2</sup> and pyridyne compete within SW/DWNT high yield T window







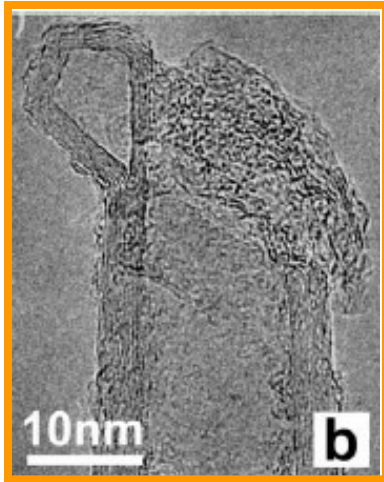
0,3% maximum  
Substitutional!!!



**A.L.Elias, P.Ayala, M.Terrones et al.**  
**Journal of Nanoscience and Nanotechnology**  
**Vol.10, 1-6, 2010**

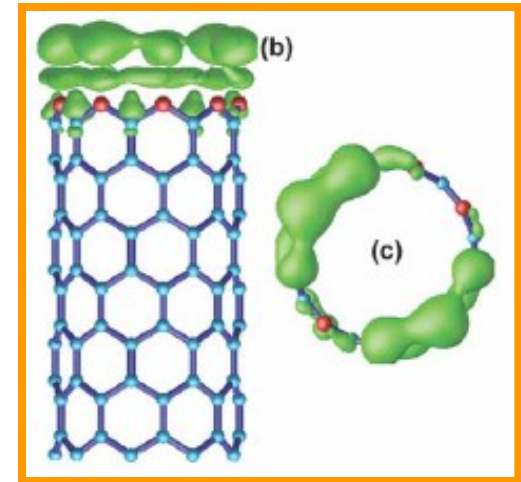
# Boron Doped Nanotubes

## MWCB<sub>x</sub>-nanotubes (Iilled Caps)



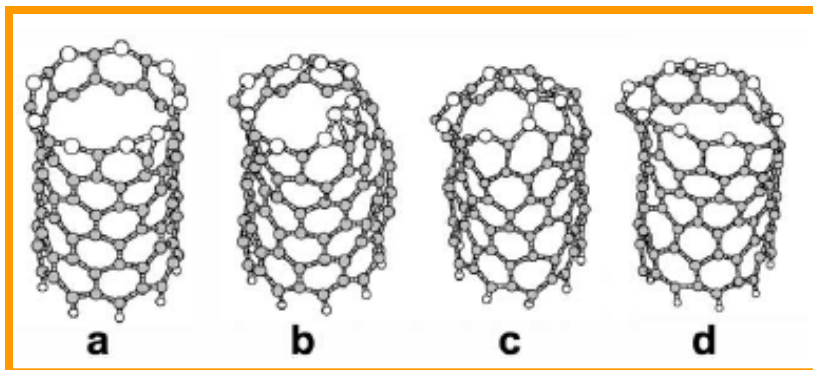
- MW-CB<sub>x</sub> nanotubes
- Straight
- Iilled caps

## Atomic Welders



*Terrones, M., et al, Materialstoday 7 (2006) 10, 30*

## SWCB<sub>x</sub>-nanotubes



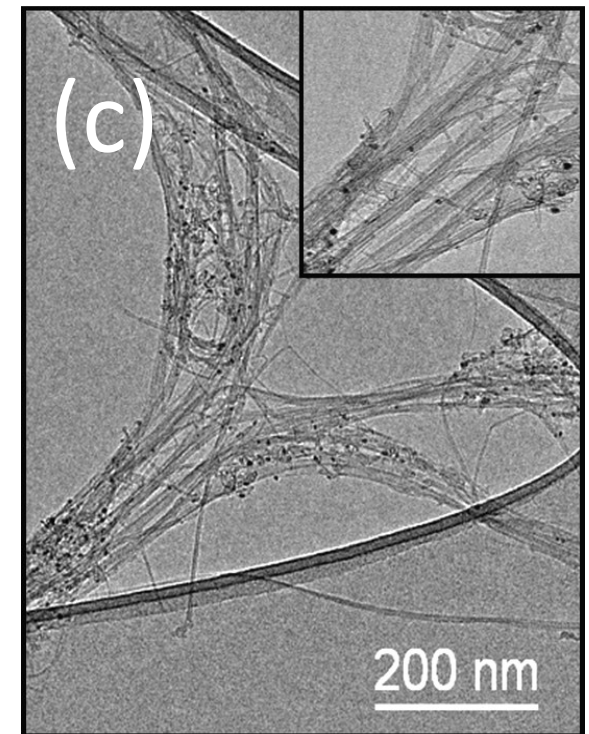
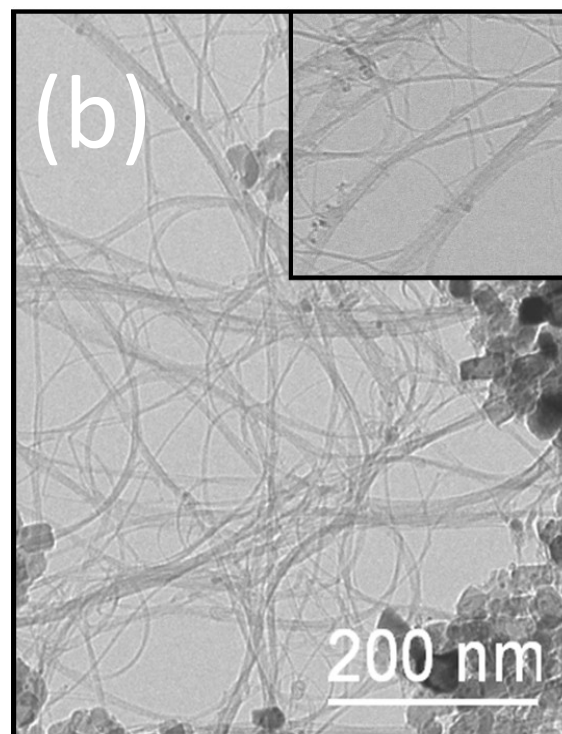
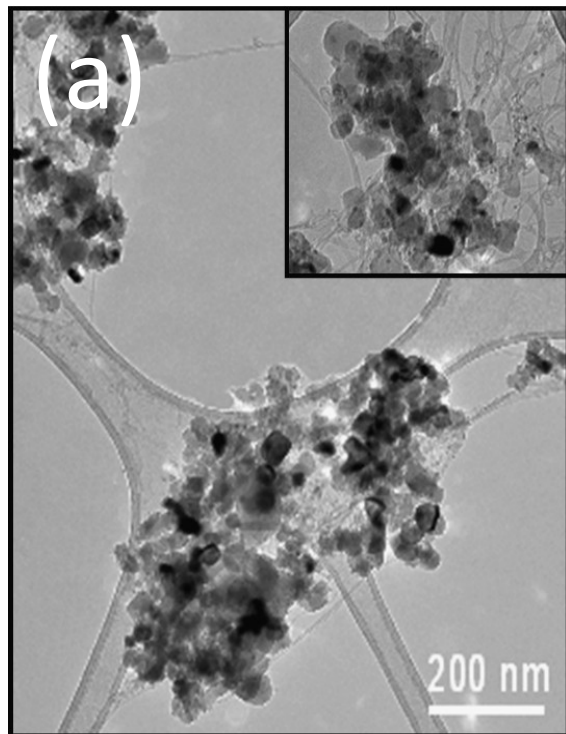
**B acts as surfactant inhibiting the closure of NTs**

*Blase et al. PRB 1998*

- SW synthesized through substitution reactions
- Doping up to 25%
- Arc Discharge-From mixture in target

# Is it possible to use a liquid feedstock for CBx-SWNTs ?

- Problem 1: Experimental Setup
- Problem 2: Precursor and Catalyst
- Problem 3: Co-products





# Nanotubes from Triisopropyl borate

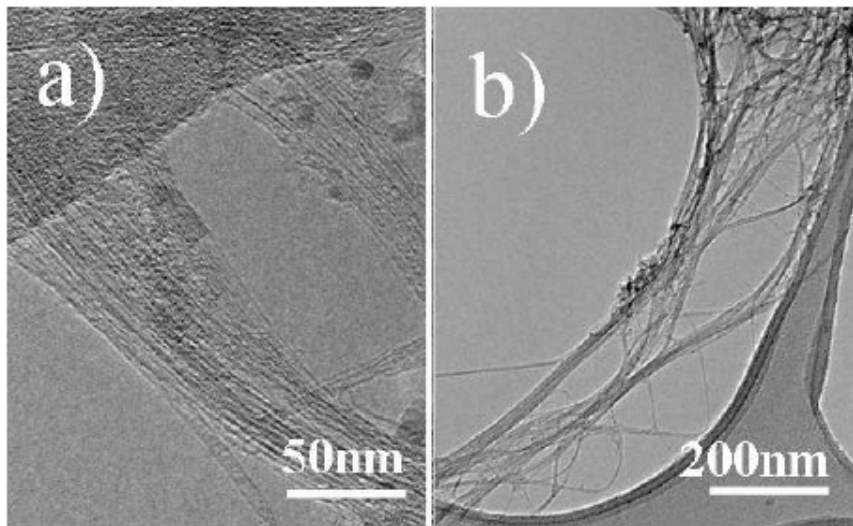
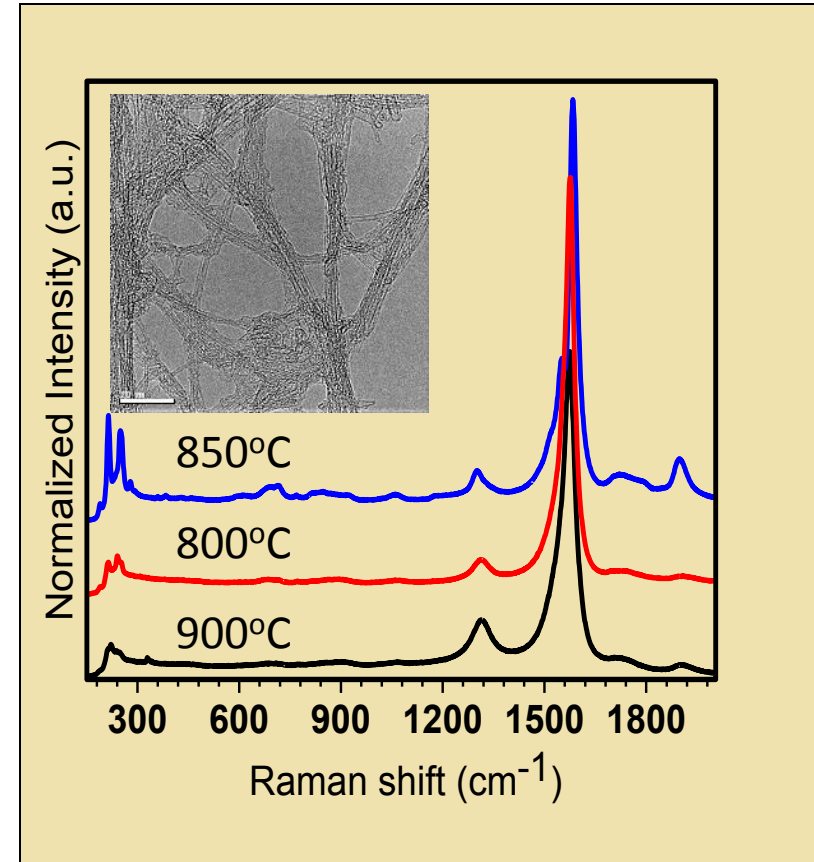
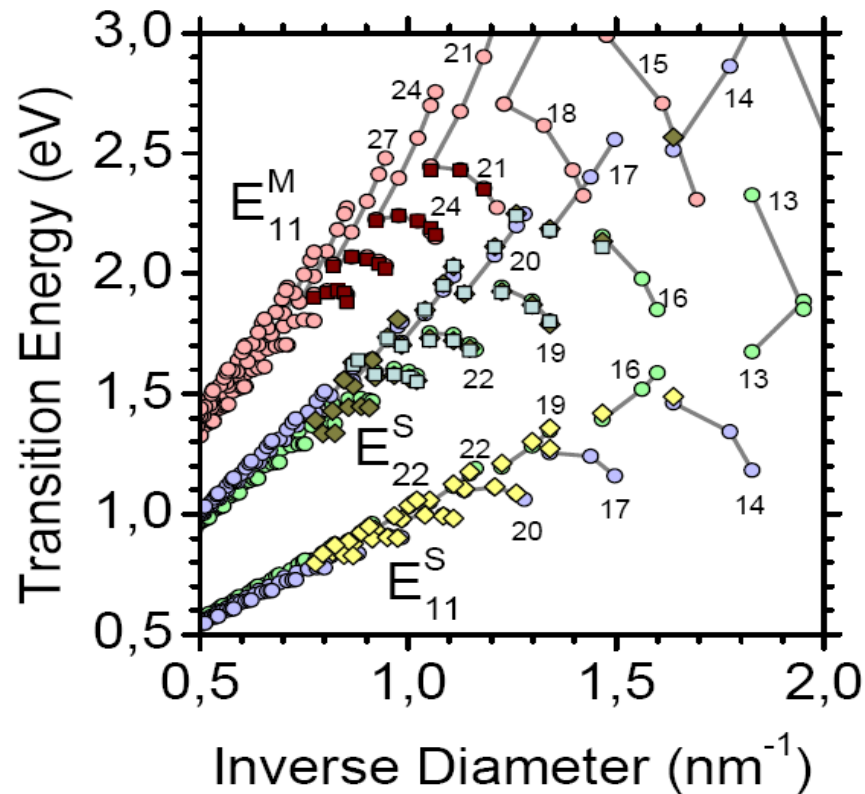


FIG. 2: Low-mag micrographs corresponding to a sample synthesized at 840°C with a supported iron based catalyst.

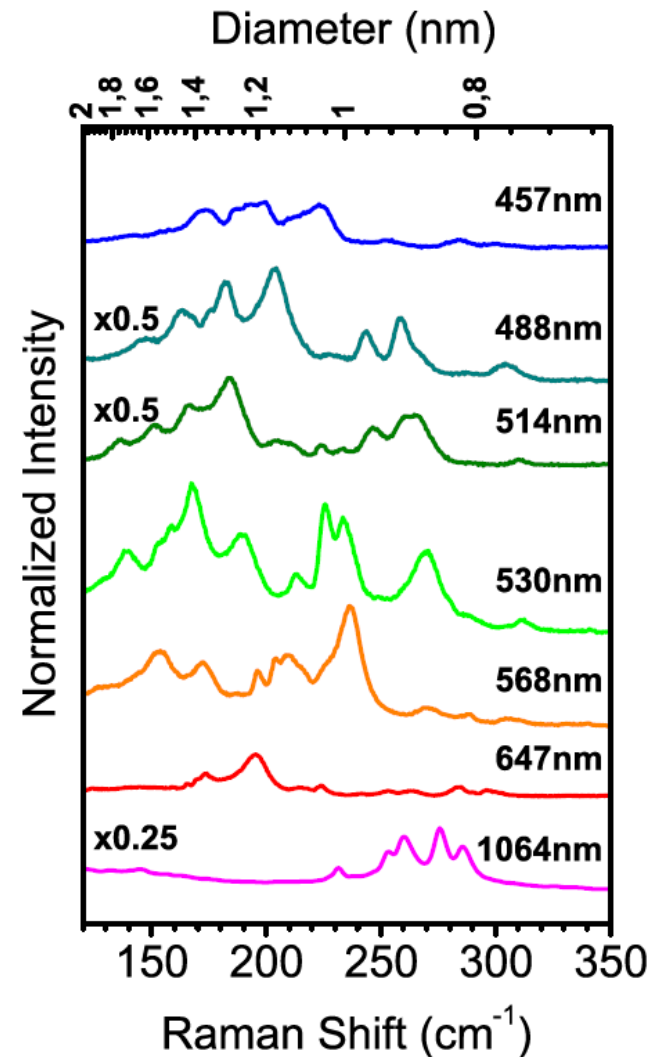




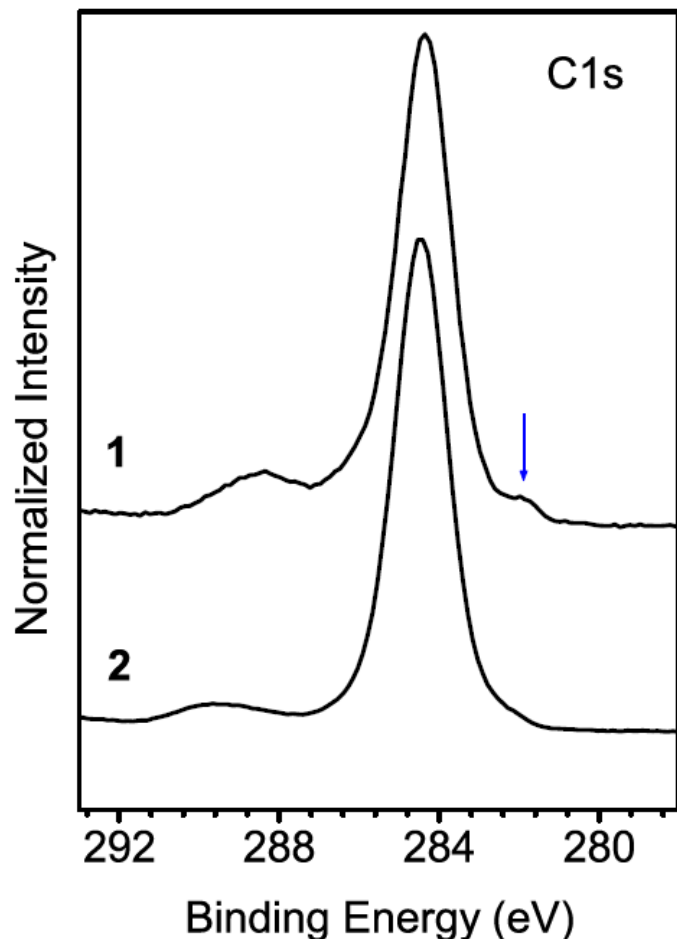
# Multifrequency Raman



Multifrequency Raman response in the RBM region with the different laser excitation energies of a samples synthesized at  $840^\circ\text{C}$



# XPS:C and B bonding environments



- C1s signal for pure SWNCNTs 284-286 eV
- C1s peak centered in 284.5 eV for B doped SWNTs samples
- Shoulder at 281.5eV (more prominent according to the B neighboring atoms)

Shirasaki et. al.

BC4 →3eV separation

Low doping occurs at lower temperatures!!!

XPS spectra of the carbon C1s binding energy for samples synthesized at 890C and 840C.

# XPS:C and B bonding environments

4 major peaks

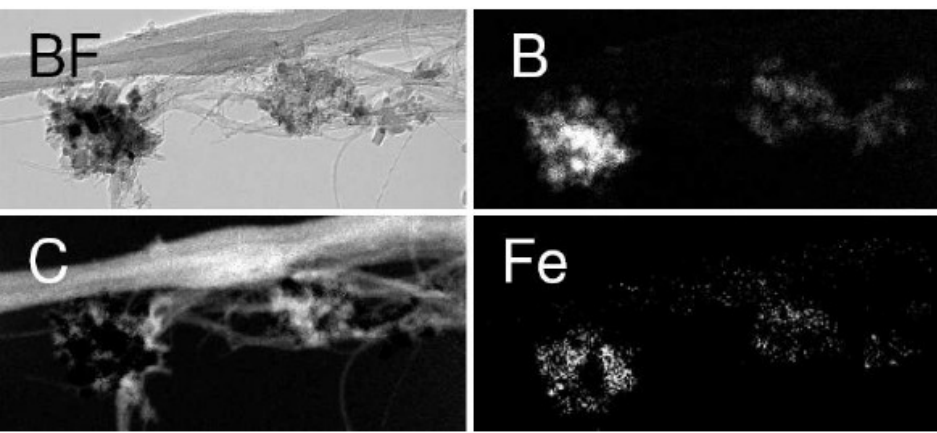
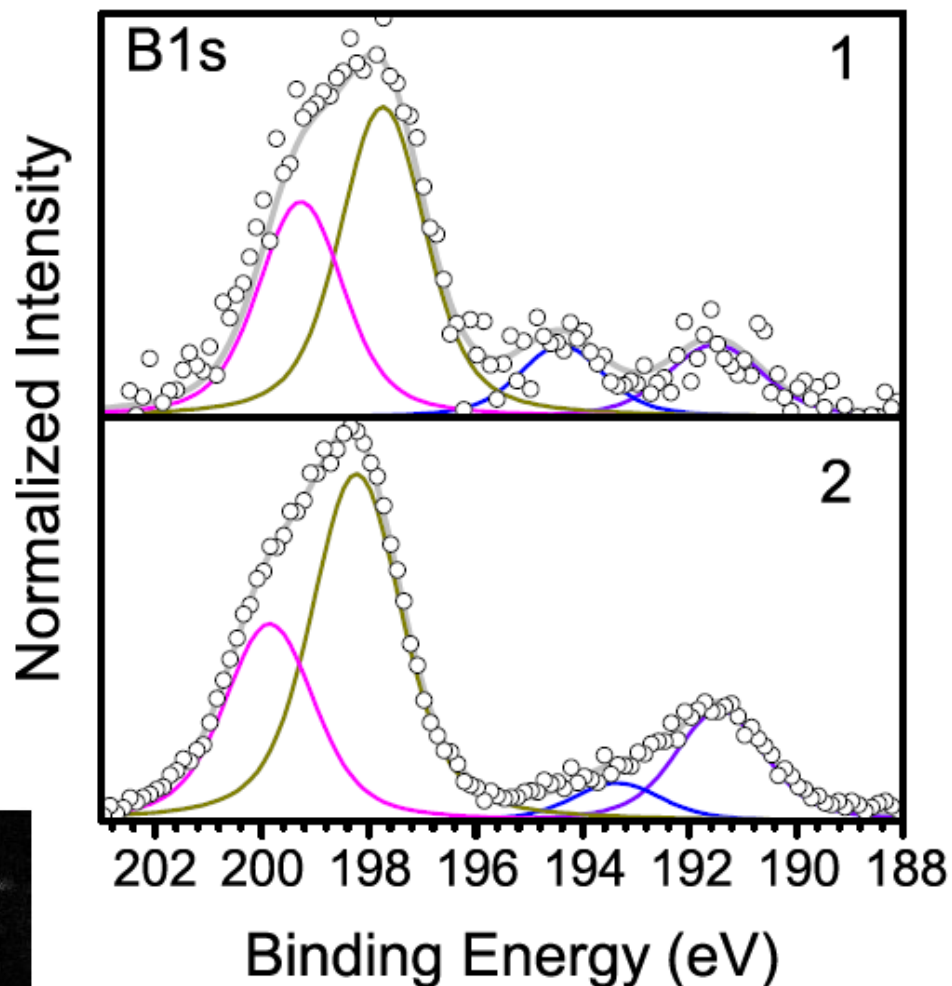
- ~191.5-192.1 Substitutional doping (Pachankarla et. al ACSNano, Nov 2007)

- ~193 Oxide formation

- Major signals

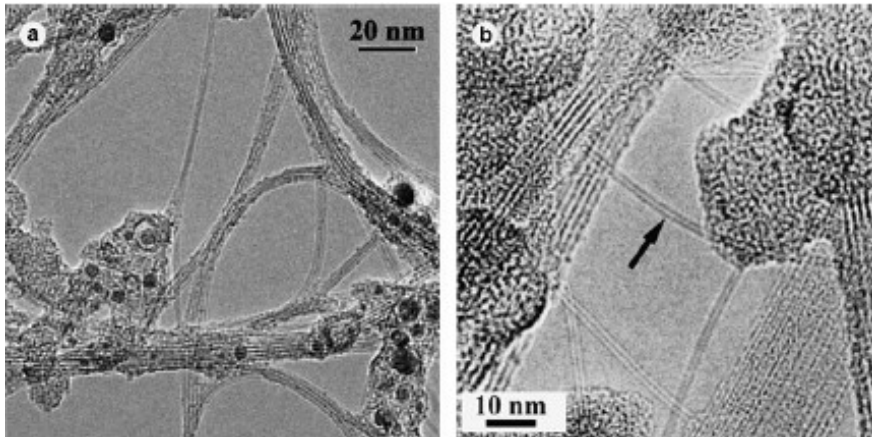
198eV and 199,5ev

B/Fe containing compounds???



P.Ayala, et al. J Mat Chem18(2008)5676

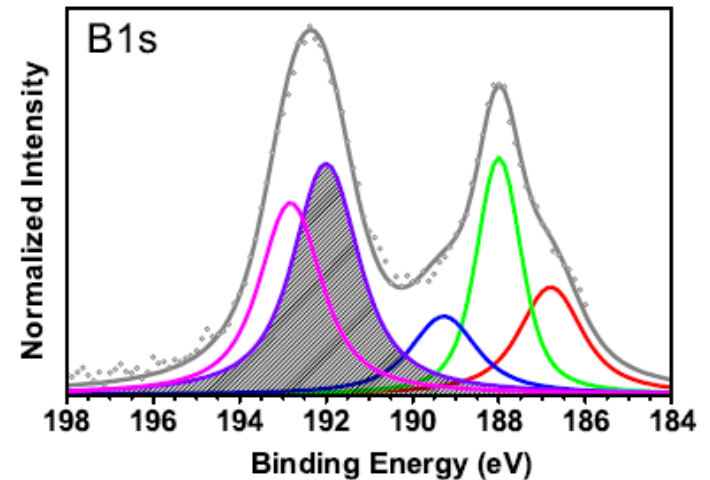
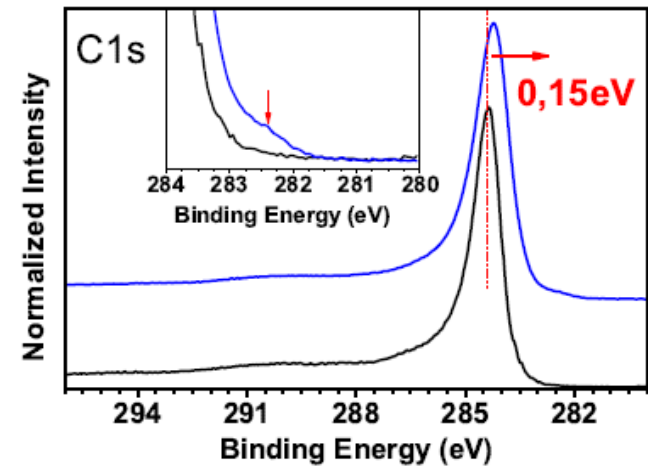
## B-doped SWCNTs with narrow diameter distribution



**Laser ablation B-doped nanotubes.** Micrographs correspond to material produced from targets with nominal boron concentrations of (a) 0 at.%, (b) 2.5 at.%.

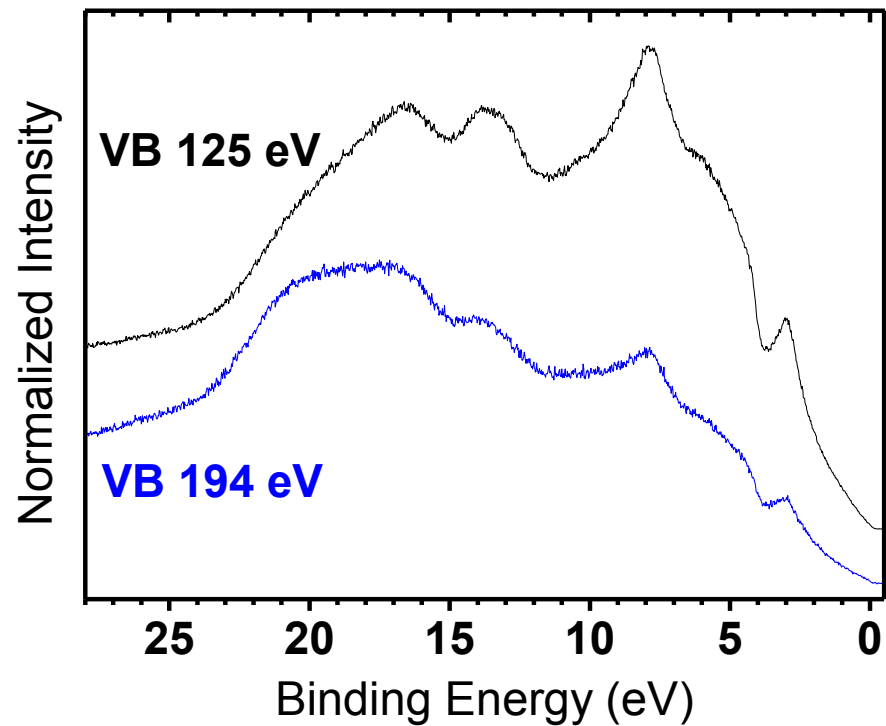
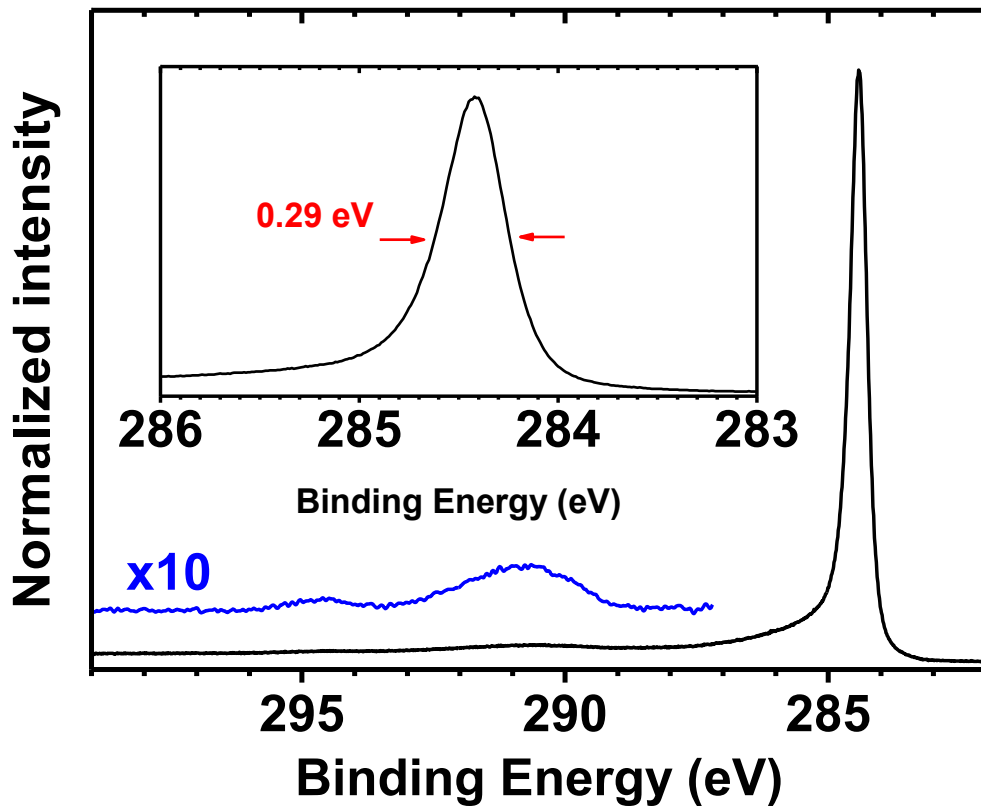
From McGuire et al. *Carbon* 43(2005) 219.

A. Rao (Clemson University)



P. Ayala et al.  
**Applied Physics Letters** 96 (2010) 18311

# Ultra low doping in B-doped SWCNTs



# Ultra low doping in B-doped SWCNTs

## C1s:

Overall shape

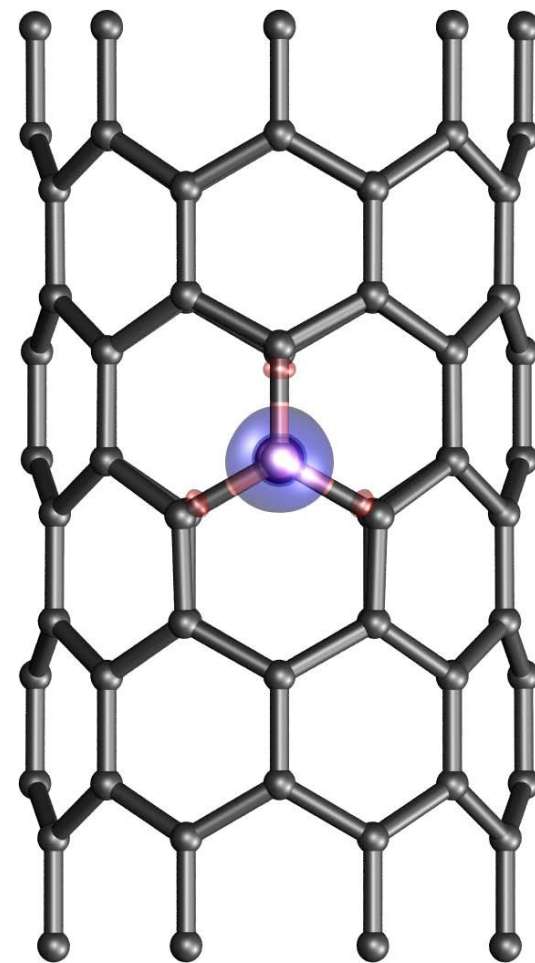
- $\pi^*$  resonance at 285.4 eV

$\sigma^*$  threshold at 291.7 eV

## B1s:

- First identification of heteroatoms in doped purified SWCNTs.

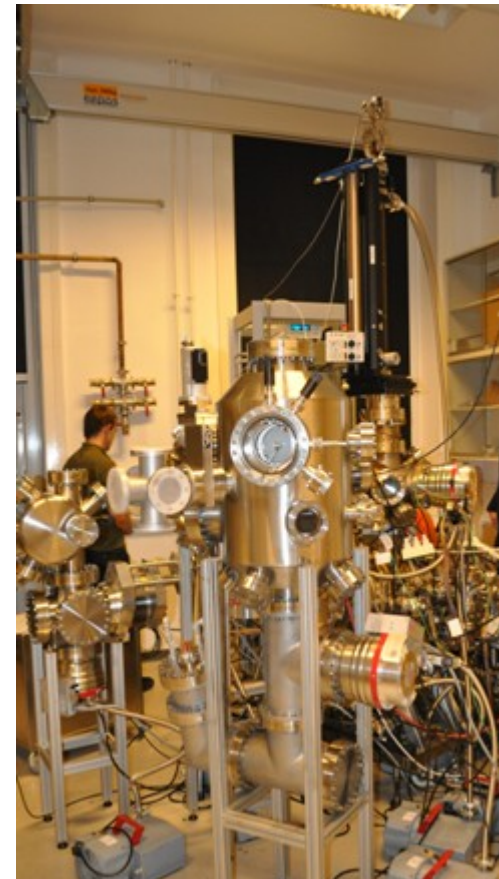
- Boron atomic concentration 0.0005% at.







A one-of-its-kind multifunctional spectrometer which includes high resolution photoemission (with XPS and ARPES) has been developed in the group. It is coupled to a multifrequency Raman and a broad range optical (1meV-6eV) setup, including preparation chambers with low temperature (He cryostats) and doping cells for in-situ doping.





# Summarizing B and N doped CNTs

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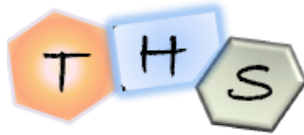
- Feasibility to use a pure feedstocks kept at room temperature to produce high quality doped SW nanotubes.
- Pure C/N feedstock, however C to N ratio of source is not reachable.
- Cleanliness of the system is crucial.
- Base pressure influences sample quality
- In absence of N gaseous forms,  $sp^2$  and pyridine compete
- Doping at very low levels (<0.5%)
- Characterize efficiently low doping levels

Techniques Implementation!!!!

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Electronic Properties of Materials

Thank you!!